Supporting Information for

Electrochemical Lithium Storage Performance of Molten

Salt Derived V₂SnC MAX Phase

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Supplementary Figures and Tables



Fig. S1 Comparison between the experimental (black crosses) and calculated XRD (red line) patterns of V₂SnC. The deviation plot (gray line) is shown in the lower part of Fig. 1a. The brown, pink, and blue ticks below the pattern represent the peak positions of the V₂SnC, Sn, and VC_x phases, respectively.

Site	Element	x	у	z	Symmetry	Wyckoff symbol
M1	V	1/3	2/3	0.0881	3m	4f
Al	Sn	1/3	2/3	0.75	-6m2	2d
C1	С	0	0	0	-3m	2a
-2.4 - i=a*v ^b					a na	

Table S1 Atomic positions in V₂SnC determined from the Rietveld refinement



Fig. S2 *b* values calculated from CVs at oxidation peaks (~0.6 V) and reduction peaks (~1.1 V). *b* value of cathodic process is 0.81 and anodic process is 0.73, suggesting the combination of diffusion-control and non-diffusion-control behavior of the V₂SnC electrode.

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Fig. S3 a XRD patterns of V₂SnC MAX phase before and after ball milling. SEM image of V₂SnC **b** before and **c** after ball milling. **d** Elemental mapping clearly proved the uniform distribution of V, Sn, and C element. **e** Particle size distribution of V₂SnC after ball milling.



Fig. S4 Electrochemical characterization of V₂SnC materials without ball milling: **a** Cyclic voltametric profiles at the 1st, and 2nd cycle at 0.1 mV s^{-1} within potential from 0.01 to 3V vs. Li/Li⁺. **b** Galvano charge-discharge profiles recorded at current densities range from 0.05 to 5 A g⁻¹. **c** Capacities and coulombic efficiency at various current densities of the electrode



Fig. S5 a *ex-situ* XRD patterns and **b** magnified XRD patterns at (002), (004) and (103) diffraction peaks of V_2 SnC electrode at different potentials



Fig. S6 SEM results of V_2 SnC electrode after long cycle electrochemical tests. **a-c** SEM image of V_2 SnC at different magnifications. **d-e** Elemental mapping clearly proved the uniform distribution of V, Sn, and C element.



Fig. S7 TEM results of V₂SnC electrode after long cycle electrochemical tests. **a** Elemental mapping of V-K α , Sn-K α and C-K α elements of V₂SnC. **b** TEM-EDS of the V₂SnC. **c**-**d** HR-TEM image and **e** Selected area electron diffraction pattern of V₂SnC



Fig. S8 TEM results of V₂SnC electrode after long cycle electrochemical tests. a TEM image and b corresponding element mapping distribution. c HR-TEM image and d magnified TEM image of V₂SnC